PATENT Attorney Docket No. ASC-049C1

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT(S):

Fitzgerald

SERIAL NO.:

10/774,890

GROUP NO.:

2818

FILING DATE:

February 9, 2004

EXAMINER:

TRAN, MAI HUONG C.

TITLE:

RELAXED SIGE PLATFORM FOR HIGH SPEED CMOS

ELECTRONICS AND HIGH SPEED ANALOG CIRCUITS

Mail Stop Petition Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450 **FAX RECEIVED**

JUN 2 4 2005

OFFICE OF PETITIONS

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Sir:

In accordance with the provisions of 37 C.F.R. 1.97 and 1.98, Applicants hereby make of record the publications listed on the accompanying Form PTO-1449, and other information contained herein, for consideration by the Examiner in connection with the examination of the above-identified patent application. In accordance with 37 C.F.R. 1.98(a)(2), only copies of the non-patent publications are enclosed.

REMARKS

In accordance with the provisions of 37 C.F.R. 1.97, this statement is being filed (CHECK ONE):

| (1) | within three (3) months of the filing date of a national application other than a continued prosecution application under 37 C.F.R. 1.53(d), or within three (3) months of the date of entry of the national stage as set forth in 37 C.F.R. 1.491 in an international application, or before the mailing of the first Office action on the merits, or before the mailing of a first Office action after the filing of a request for continued examination under 37 C.F.R. 1.114; or |
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| (2) | after the period defined in (1) but before the mailing date of a final action or a notice of allowance under 37 C.F.R. 1.311, and |
| | the requisite Statement is below, OR |
| | the requisite fee under 37 C.F.R. 1.17(p), namely \$180.00, is included herein, or |

Supplemental Information Disclosure Statement Serial No. 10/774,890 Page 2 of 2 after the mailing date of a final action or notice of allowance but before the payment (3) of the issue fee, AND the requisite Statement is below, AND the requisite petition fee under 37 C.F.R. 1.17(p), namely \$180.00 is included herein. It is respectfully requested that each of the patents and publications listed on the attached Form PTO-1449, and other information contained herein, be made of record in this application. **STATEMENT** As required under 37 C.F.R. 1.97(e), Applicant(s), through the undersigned, hereby state either that [check the appropriate space only if either (2) or (3) is checked on the previous page and the Statement is required]: Each item of information contained in the Information Disclosure Statement was 1. first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the Information Disclosure Statement; or No item of information contained in the Information Disclosure Statement was 2. cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing this Statement after making reasonable inquiry, no item of information contained in the Information Disclosure Statement was known to any individual designated in 37 C.F.R. 1.56(c) more than three months prior to the filing of the Information Disclosure Statement. Respectfully submitted, C. U Date: June 24, 2005 Reg. No. 44,381 Natasha C. Us Attorney for Applicant Goodwin Procter LLP Exchange Place Tel. No.: (617) 570-1806

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